NSN 5961-01-065-6481

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View Online at https://aerobasegroup.com/nsn/5961-01-065-6481 **Inclosure Material:** Metal **Overall Length:** 0.450 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 105.0 regulator voltage **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 115.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius case **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Leads gold **Precious Material:** Gold **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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